NSN 5961-01-099-8275

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View Online at https://aerobasegroup.com/nsn/5961-01-099-8275 **Inclosure Material:** Metal and glass **Overall Length:** 38.69 millimeters **Overall Height:** 11.4 millimeters **Overall Width:** 26.66 millimeters **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-204aa **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 15.00 amperes zero-gate-voltage source current blank and 1.00 milliamperes zero-gate-voltage source current preset **Power Rating Per Characteristic:** 175.0 watts small-signal input power, common-collector absolute **Transfer Ratio:** 8.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: